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# SSN1N45B

## N-Channel B-FET

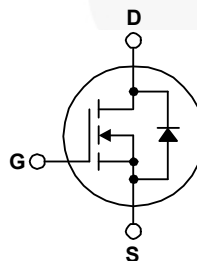
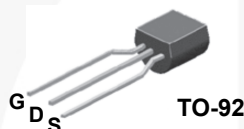
450 V, 0.5 A, 4.25  $\Omega$

### Description

These N-Channel enhancement mode power field effect transistors are produced using Fairchild's proprietary, planar, DMOS technology. This advanced technology has been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode. These devices are well suited for electronic ballasts based on half bridge configuration.

### Features

- 0.5 A, 450 V,  $R_{DS(on)} = 4.25 \Omega @ V_{GS} = 10 \text{ V}$
- Low Gate Charge (typical 6.5 nC)
- Low  $C_{rss}$  (typical 6.5 pF)
- 100% Avalanche Tested
- Improved dv/dt Capability
- Gate-Source Voltage  $\pm 50\text{V}$  Guaranteed



### Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	SSN1N45BTA	Unit
$V_{DSS}$	Drain-Source Voltage	450	V
$I_D$	Drain Current - Continuous ( $T_C = 25^\circ\text{C}$ )	0.5	A
	- Continuous ( $T_C = 100^\circ\text{C}$ )	0.32	A
$I_{DM}$	Drain Current - Pulsed (Note 1)	4.0	A
$V_{GSS}$	Gate-Source Voltage	$\pm 50$	V
$E_{AS}$	Single Pulsed Avalanche Energy (Note 2)	108	mJ
$I_{AR}$	Avalanche Current (Note 1)	0.5	A
$E_{AR}$	Repetitive Avalanche Energy (Note 1)	0.25	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)	5.5	V/ns
$P_D$	Power Dissipation ( $T_A = 25^\circ\text{C}$ )	0.9	W
	Power Dissipation ( $T_L = 25^\circ\text{C}$ )	2.5	W
	- Derate above $25^\circ\text{C}$	0.02	W/ $^\circ\text{C}$
$T_J, T_{stg}$	Operating and Storage Temperature Range	-55 to +150	$^\circ\text{C}$
$T_L$	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds	300	$^\circ\text{C}$

### Thermal Characteristics

Symbol	Parameter	SSN1N45BTA	Unit
$R_{\theta JL}$	Thermal Resistance, Junction-to-Lead, Max. (Note 5a)	50	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max. (Note 5b)	140	$^\circ\text{C/W}$

## Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
SSN1N45BTA	1N45B	TO-92	AMMO	N/A	N/A	2000 units

## Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
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### Off Characteristics

$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_D = 250\text{ }\mu\text{A}$	450	--	--	V
$\Delta BV_{DSS} / \Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = 250\text{ }\mu\text{A}$ , Referenced to $25^\circ\text{C}$	--	0.5	--	V/ $^\circ\text{C}$
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 450\text{ V}, V_{GS} = 0\text{ V}$	--	--	10	$\mu\text{A}$
		$V_{DS} = 360\text{ V}, T_C = 125^\circ\text{C}$	--	--	100	$\mu\text{A}$
$I_{GSSF}$	Gate-Body Leakage Current, Forward	$V_{GS} = 50\text{ V}, V_{DS} = 0\text{ V}$	--	--	100	nA
$I_{GSSR}$	Gate-Body Leakage Current, Reverse	$V_{GS} = -50\text{ V}, V_{DS} = 0\text{ V}$	--	--	-100	nA

### On Characteristics

$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\text{ }\mu\text{A}$	2.3	3.0	3.7	V
		$V_{DS} = V_{GS}, I_D = 250\text{ mA}$	3.5	4.2	4.9	V
$R_{DS(on)}$	Static Drain-Source On-Resistance	$V_{GS} = 10\text{ V}, I_D = 0.25\text{ A}$	--	3.4	4.25	$\Omega$
$g_{FS}$	Forward Transconductance	$V_{DS} = 50\text{ V}, I_D = 0.25\text{ A}$	--	0.7	--	S

### Dynamic Characteristics

$C_{iss}$	Input Capacitance	$V_{DS} = 25\text{ V}, V_{GS} = 0\text{ V},$ $f = 1.0\text{ MHz}$	--	185	240	pF
$C_{oss}$	Output Capacitance		--	29	40	pF
$C_{rss}$	Reverse Transfer Capacitance		--	6.5	8.5	pF

### Switching Characteristics

$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 225\text{ V}, I_D = 0.5\text{ A},$ $R_G = 25\text{ }\Omega$  (Note 4)	--	7.5	25	ns
$t_r$	Turn-On Rise Time		--	21	50	ns
$t_{d(off)}$	Turn-Off Delay Time		--	23	55	ns
$t_f$	Turn-Off Fall Time		--	36	80	ns
$Q_g$	Total Gate Charge	$V_{DS} = 360\text{ V}, I_D = 0.5\text{ A},$ $V_{GS} = 10\text{ V}$  (Note 4)	--	6.5	8.5	nC
$Q_{gs}$	Gate-Source Charge		--	0.9	--	nC
$Q_{gd}$	Gate-Drain Charge		--	3.2	--	nC

### Drain-Source Diode Characteristics and Maximum Ratings

I <sub>S</sub>	Maximum Continuous Drain-Source Diode Forward Current		--	--	0.5	A
I <sub>SM</sub>	Maximum Pulsed Drain-Source Diode Forward Current		--	--	4.0	A
V <sub>SD</sub>	Drain-Source Diode Forward Voltage	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 0.5 A	--	--	1.4	V
t <sub>rr</sub>	Reverse Recovery Time	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 0.5 A,	--	102	--	ns
Q <sub>rr</sub>	Reverse Recovery Charge	dI <sub>F</sub> / dt = 100 A/μs	--	0.26	--	μC

#### Notes:

1. Repetitive Rating : Pulse width limited by maximum junction temperature.
2.  $L = 75\text{ mH}, I_{AS} = 1.6\text{ A}, V_{DD} = 50\text{ V}, R_G = 25\text{ }\Omega$ , starting  $T_J = 25^\circ\text{C}$ .
3.  $I_{SD} \leq 0.5\text{ A}, dI/dt \leq 300\text{ A}/\mu\text{s}, V_{DD} \leq BV_{DSS}$ , starting  $T_J = 25^\circ\text{C}$ .
4. Essentially independent of operating temperature.
5. a) Reference point of the  $R_{\theta JA}$  is the drain lead.  
b) When mounted on 3"x4.5" FR-4 PCB without any pad copper in a still air environment.  
( $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance.  $R_{\theta CA}$  is determined by the user's board design)

## Typical Characteristics

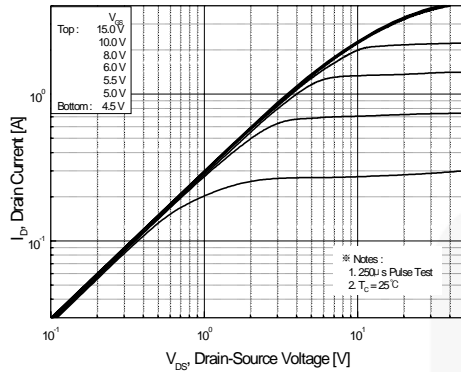


Figure 1. On-Region Characteristics

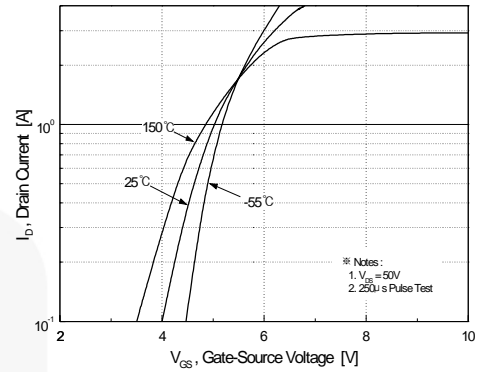


Figure 2. Transfer Characteristics

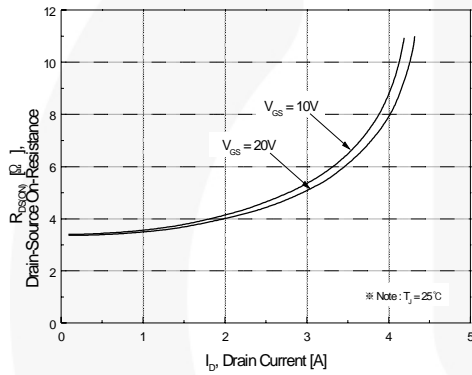


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

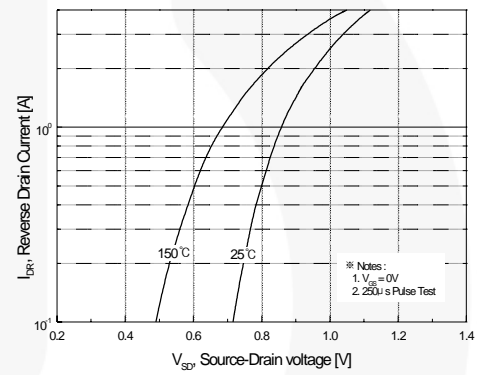


Figure 4. Body Diode Forward Voltage Variation with Source Current and Temperature

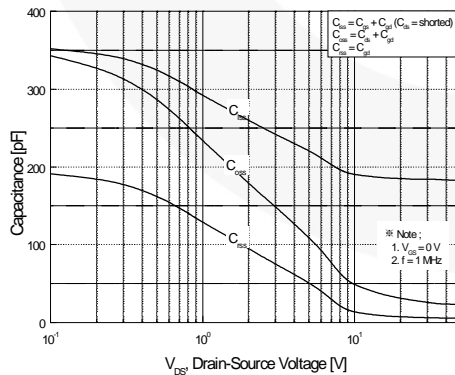


Figure 5. Capacitance Characteristics

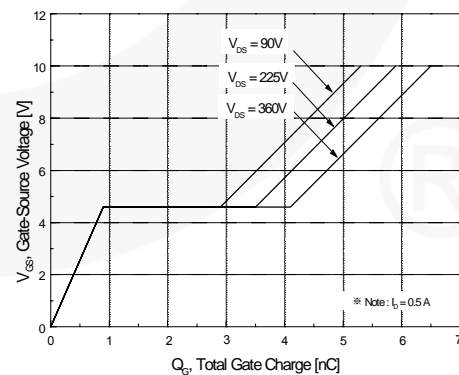


Figure 6. Gate Charge Characteristics

## Typical Characteristics (continued)

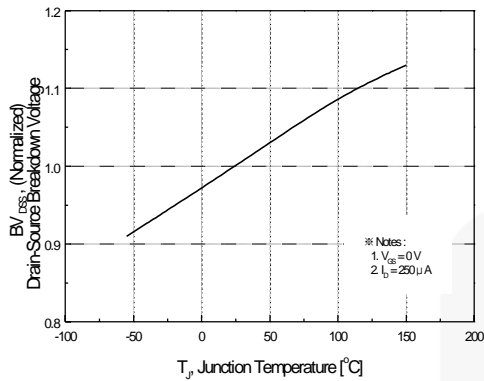


Figure 7. Breakdown Voltage Variation vs. Temperature

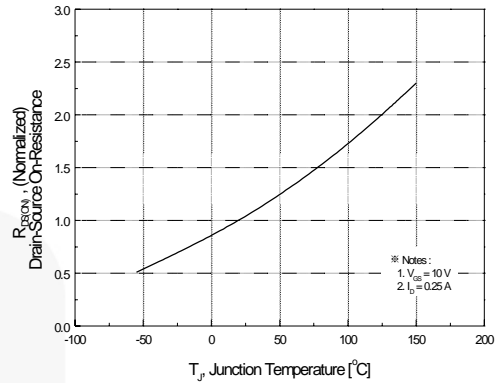


Figure 8. On-Resistance Variation vs. Temperature

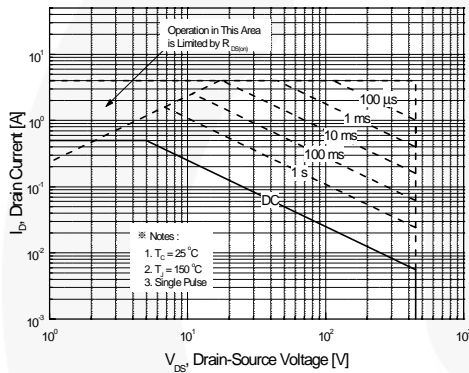


Figure 9. Maximum Safe Operating Area

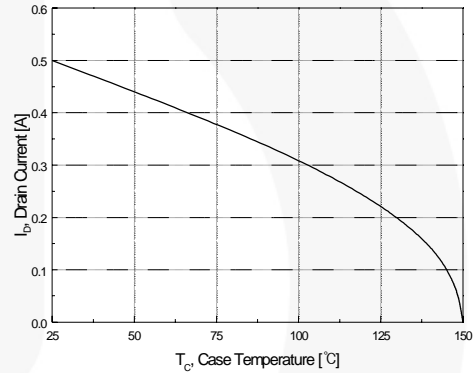


Figure 10. Maximum Drain Current vs. Case Temperature

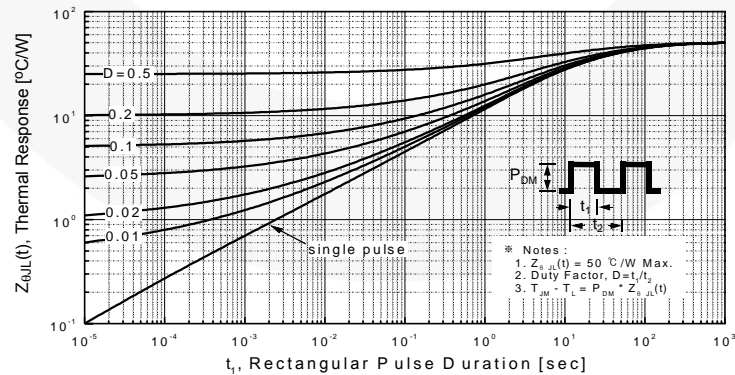


Figure 11. Transient Thermal Response Curve

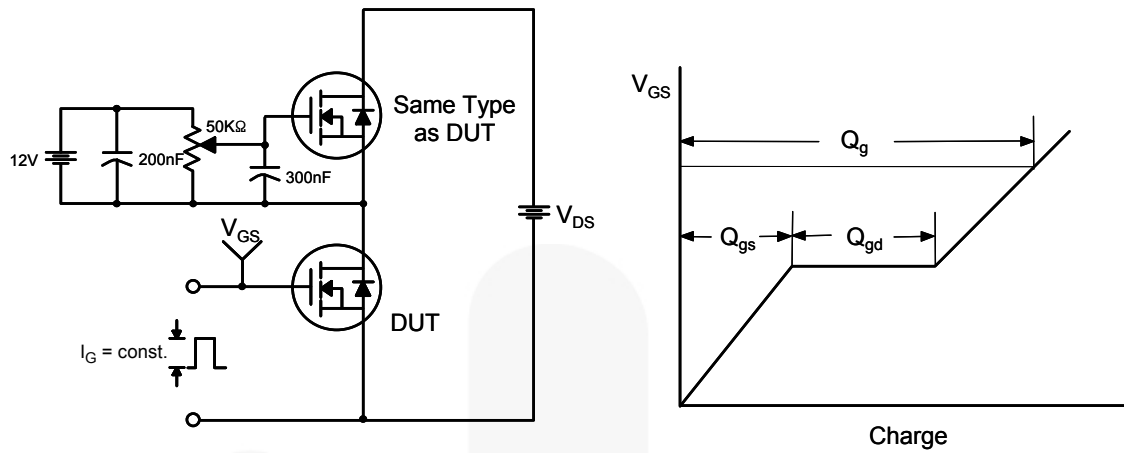


Figure 12. Gate Charge Test Circuit & Waveform

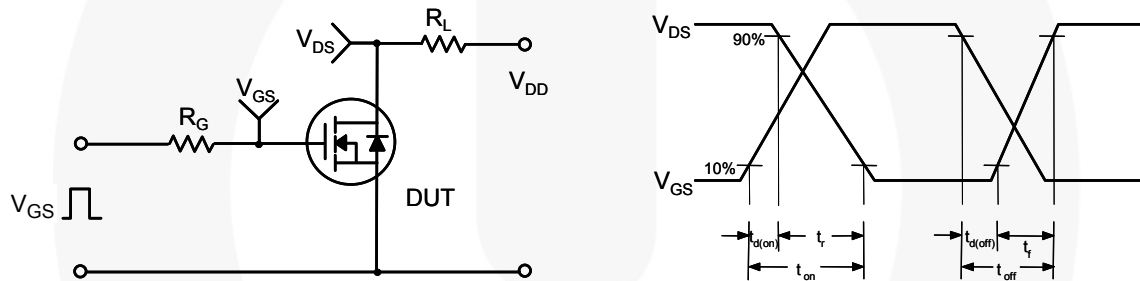


Figure 13. Resistive Switching Test Circuit & Waveforms

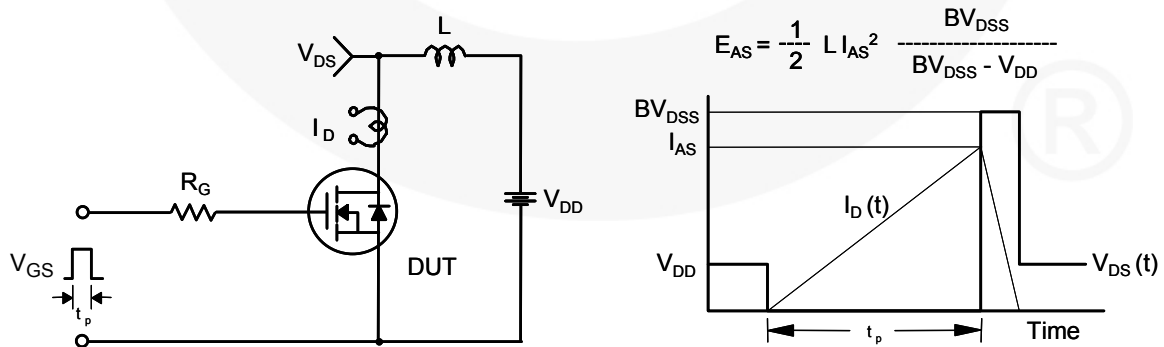


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms





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B. ALL DIMENSIONS ARE IN MILLIMETERS.  
C. DRAWING CONFORMS TO ASME Y14.5M-2009.  
D. DRAWING FILENAME: MKT-ZA03FREV3.  
E. FAIRCHILD SEMICONDUCTOR.

**Figure 16. TO92, Molded, 3-Lead, 0.200 In Line Spacing LD Form ( J61Z Option)**

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